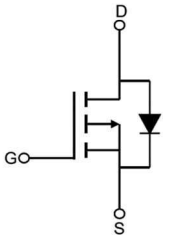
AP30P06K

P-Channel Enhancement Mosfet

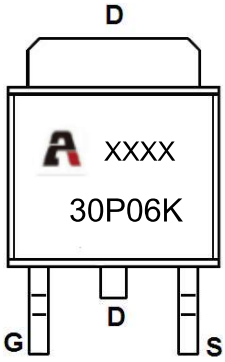
DATA SHEET

Feature

- -60V,-30A
  $R_{DS(ON)}$ <33mΩ @V_{GS}=-10V TYP:27 mΩ
  $R_{DS(ON)}$ <40mΩ @V_{GS}=-4.5V TYP:33 mΩ
- Advanced Trench Technology
- Lead free product is acquired
- Excellent $R_{DS(ON)}$ and Low Gate Charge



Schematic Diagram



Marking and pin assignment

Application

- PWM applications
- Load Switch
- Power management

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
30P06K	AP30P06K	TO-252	13 inch	-	2500

ABSOLUTE MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-60	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current (T_a =25℃)	I_D	-30	A
Continuous Drain Current (T_a =100℃)	I_D	-20	A
Pulsed Drain Currenr (1)	I_{DM}	-120	A
Singel Pulsed Avalanche Energy (2)	E_{AS}	90	mJ
Power Dissipation	P_D	51	W
Thermal Resistance from Junction to Case	$R_{\theta JC}$	3.0	℃/W
Junction Temperature	T_J	150	℃
Storage Temperature	T_{STG}	-55~ +150	℃

MOSFET ELECTRICAL CHARACTERISTICS(T_a=25℃ unless otherwise noted)

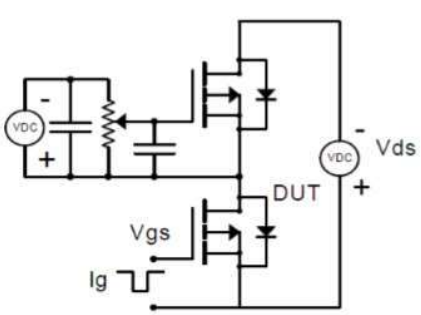
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D =-250μA	-60	-	-	V
Zero gate voltage drain current	I_{DSS}	V_{DS} =-60V, V_{GS} = 0V	-	-	1	μA
Gate-body leakage current	I_{GSS}	V_{GS} =±20V, V_{DS} = 0V	-	-	±100	nA
Gate threshold voltage(3)	$V_{GS(th)}$	V_{DS} =V_{GS}, I_D =-250μA	-1	-1.7	-2.5	V
Drain-source on-resistance(3)	$R_{DS(on)}$	V_{GS} =-10V, I_D =-15A	-	27	33	mΩ
		V_{GS} =-4.5V, I_D =-10A	-	33	40	
Dynamic characteristics						
Input Capacitance	C_{iss}	V_{DS} =-25V, V_{GS} =0V, f =1MHz	-	2400	-	pF
Output Capacitance	C_{oss}		-	251	-	
Reverse Transfer Capacitance	C_{rss}		-	196	-	
Switching characteristics						
Turn-on delay time	$t_{d(on)}$	V_{DD}=-30V, I_D=-30A, R_L=3Ω V_{GS}=-10V, R_G=3Ω	-	15	-	ns
Turn-on rise time	t_r		-	120	-	
Turn-off delay time	$t_{d(off)}$		-	245	-	
Turn-off fall time	t_f		-	199	-	
Total Gate Charge	Qg	VDS=-30V, ID=-15A, VGS=-10V	-	49	-	nC
Gate-Source Charge	Qgs		-	8	-	
Gate-Drain Charge	Qgd		-	12	-	
Source-Drain Diode characteristics						
Diode Forward voltage(2)	V_{DS}	V_{GS} =0V, I_S=-10A	-	-	-1.2	V
Diode Forward current(3)	I_S		-	-	-30	A

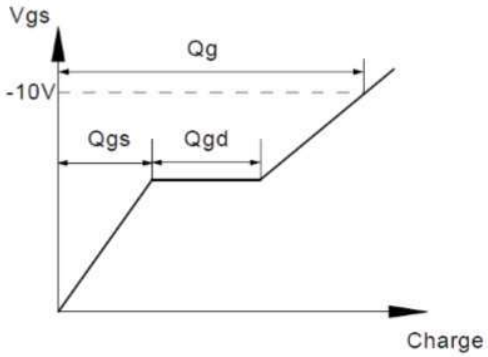
Notes:

1. Repetitive Rating: pulse width limited by maximum junction temperature
2. EAS Condition:T_J=25℃,V_{DD}=-30V,R_G=20Ω,L=0.5mH
3. Pulse Test: pulse width≤300μs, duty cycle≤2%
4. Surface Mounted on FR4 Board,t≤10 sec

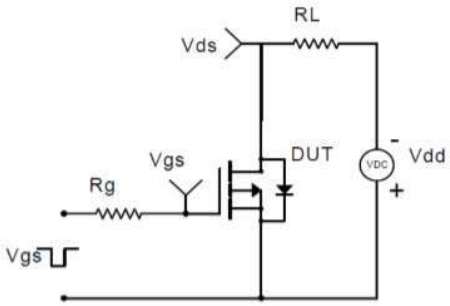
Test Circuit

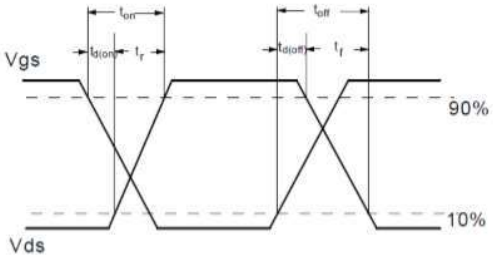
Gate Charge Test Circuit & Waveform



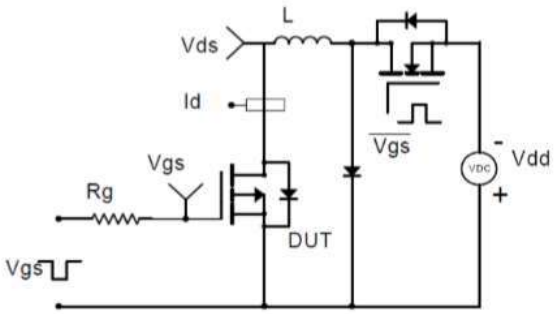


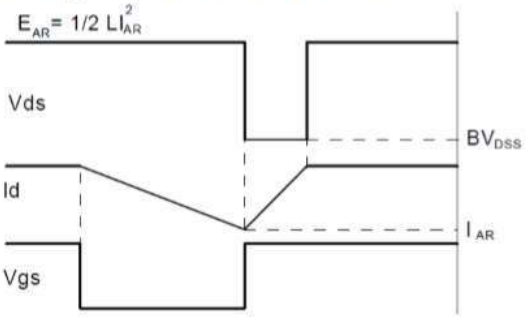
Resistive Switching Test Circuit & Waveforms



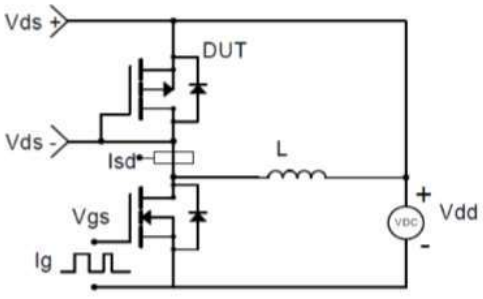


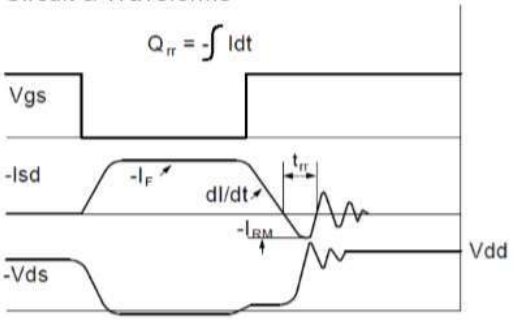
Unclamped Inductive Switching (UIS) Test Circuit & Waveforms





Diode Recovery Test Circuit & Waveforms





Typical Performance Characteristics

Figure1: Output Characteristics

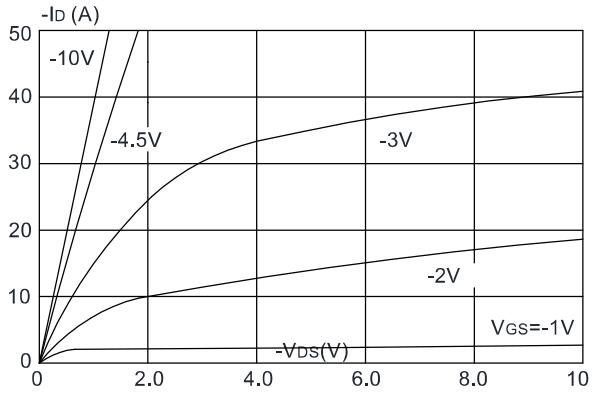


Figure 2: Typical Transfer Characteristics

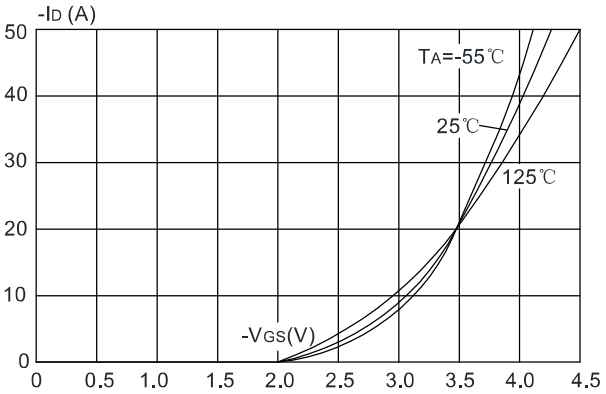


Figure 3: On-resistance vs. Drain Current

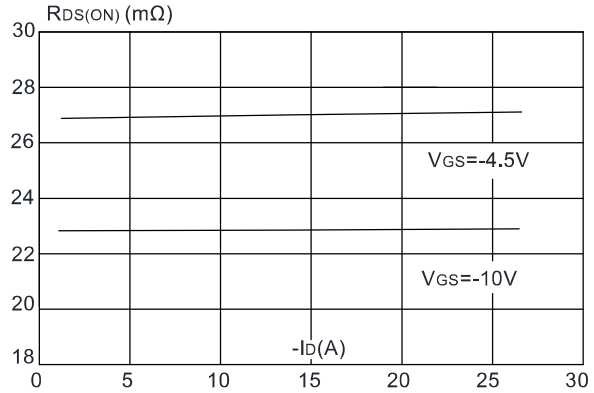


Figure 4: Body Diode Characteristics

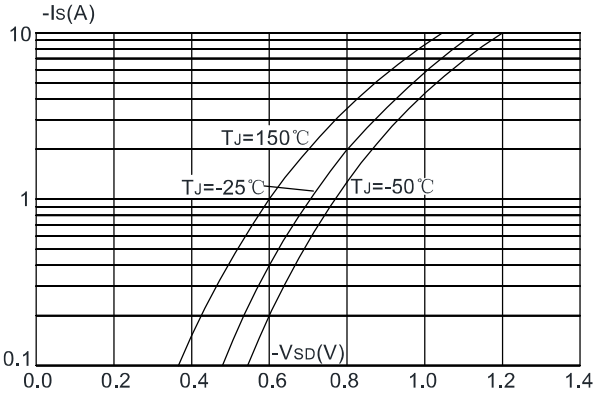


Figure 5: Gate Charge Characteristics

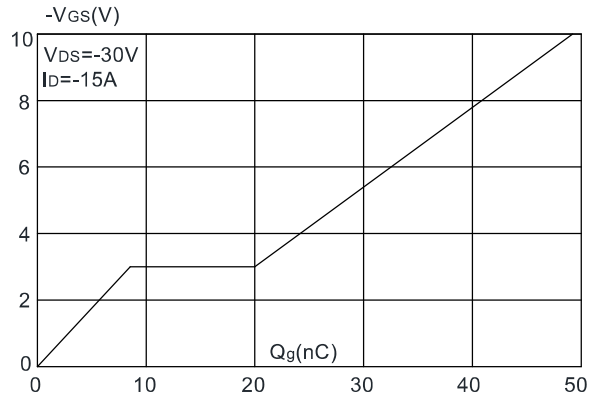


Figure 6: Capacitance Characteristics

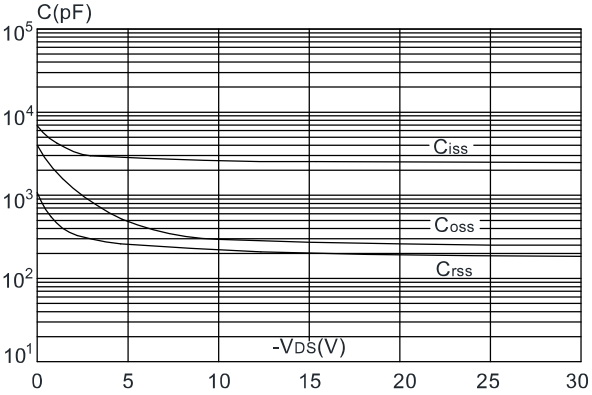


Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

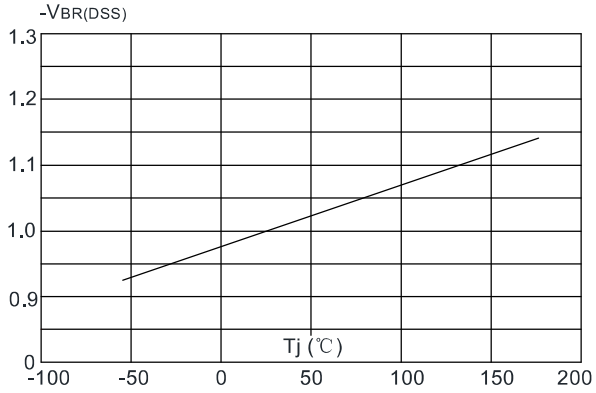


Figure 8: Normalized on Resistance vs. Junction Temperature

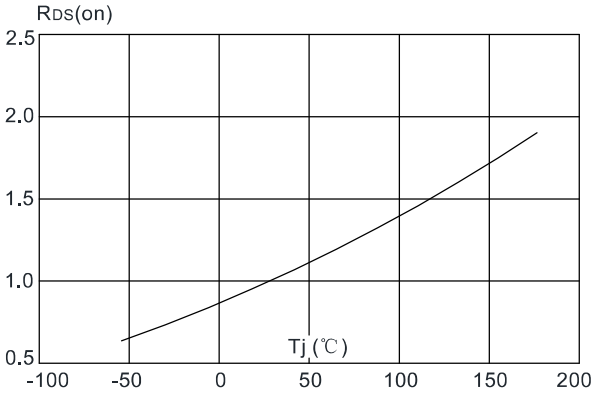


Figure 9: Maximum Safe Operating Area

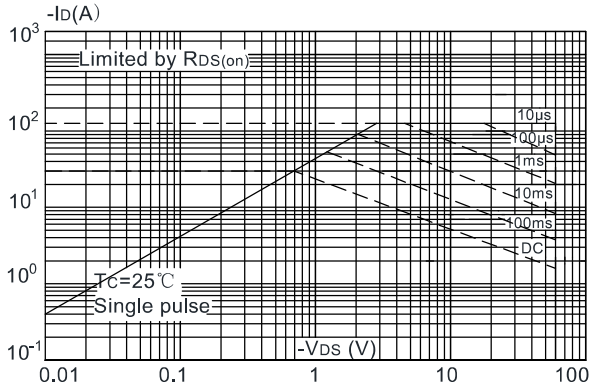


Figure 10: Maximum Continuous Drain Current vs. Case Temperature

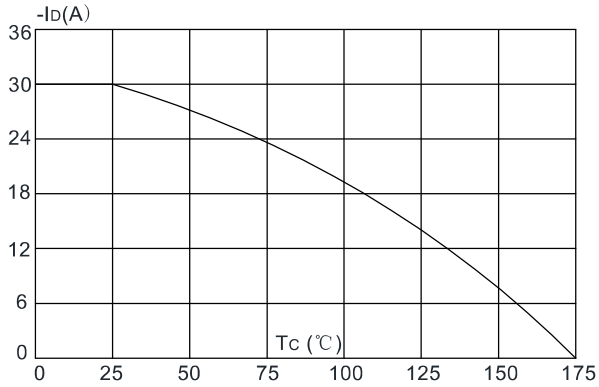
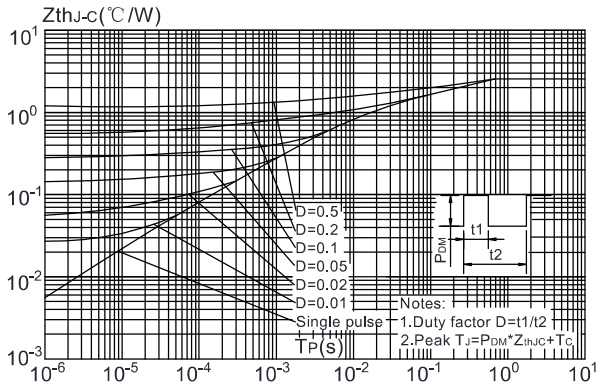
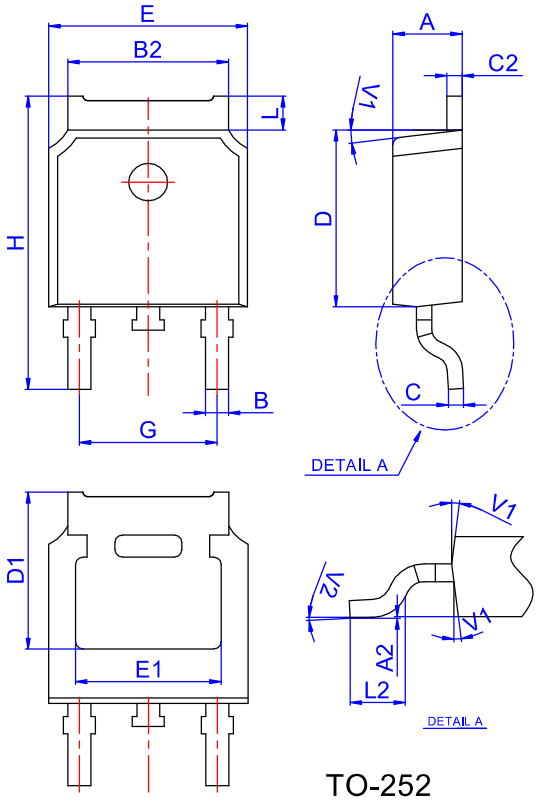


Figure.11: Maximum Effective Transient Thermal Impedance, Junction-to-Case



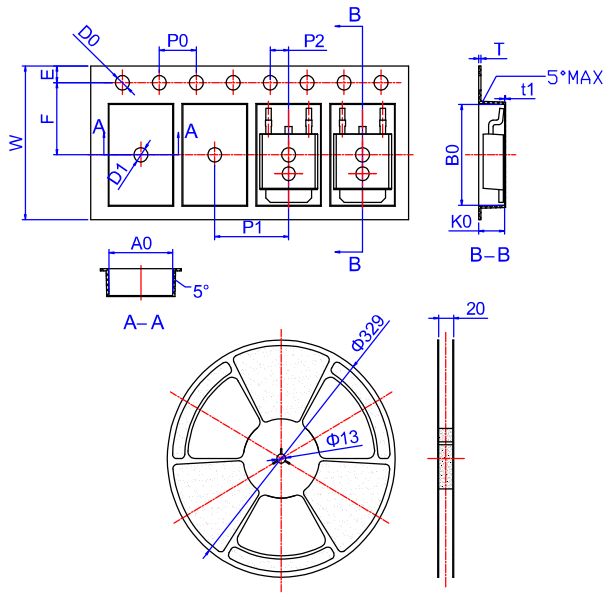
TO-252 Package Information



TO-252

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

Reel Specification-TO-252



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	15.90	16.00	16.10	0.626	0.630	0.634
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
D0	1.40	1.50	1.60	0.055	0.059	0.063
D1	1.40	1.50	1.60	0.055	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
A0	6.85	6.90	7.00	0.270	0.271	0.276
B0	10.45	10.50	10.60	0.411	0.413	0.417
K0	2.68	2.78	2.88	0.105	0.109	0.113
T	0.24		0.27	0.009		0.011
t1	0.10			0.004		
10P0	39.80	40.00	40.20	1.567	1.575	1.583